7-SEGMEN

12



Data sheet acquired from Harris Semiconductor SCHS072B – Revised July 2003

CMOS BCD-to-7-Segment Latch Decoder Drivers

High-Voltage Types (20-Volt Rating)





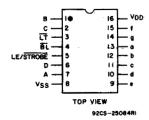
200 - 25097

CD4511B types are BCD-to-7-segment latch decoder drivers constructed with CMOS logic and n-p-n bipolar transistor output devices on a single monolithic structure. These devices combine the low quiescent power dissipation and high noise immunity features of RCA CMOS with n-p-n bipolar output transistors capable of sourcing up to 25 mA. This capability allows the CD4511B types to drive LED's and other displays directly.

Lamp Test (LT), Blanking (BL), and Latch Enable or Strobe inputs are provided to test the display, shut off or intensity-modulate it, and store or strobe a BCD code, respectively. Several different signals may be multiplexed and displayed when external multiplexing circuitry is used.

The CD4511B types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (NSR suffix), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

These devices are similar to the type MC14511.



CD4511B TERMINAL ASSIGNMENT

Features:

- High-output-sourcing capability up to 25 mA
- Input latches for BCD Code storage
- Lamp Test and Blanking capability
- 7-segment outputs blanked for BCD input codes > 1001
- 100% tested for quiescent current at 20 V
- Max. input current of 1 μA at 18 V, over full package-temperature range, 100 nA at 18 V and 25°C
- 5-V, 10-V, and 15-V parametric ratings

Applications:

Driving common-cathode LED displays

V_{SS}=8 V_{DD}=16

FUNCTIONAL DIAGRAM

- Multiplexing with common-cathode LED displays
- Driving incandescent displays

CD4511B Types

■ Driving low-voltage fluorescent displays

MAXIMUM RATINGS, Absolute-Maximum Values: DC SUPPLY-VOLTAGE RANGE, (VDD) Voltages referenced to VSS Terminal) -0.5V to +20V INPUT VOLTAGE RANGE, ALL INPUTS -0.5V to VDD +0.5V DC INPUT CURRENT, ANY ONE INPUT ±10mA POWER DISSIPATION PER PACKAGE (PD): For TA = -55°C to +100°C For TA = +100°C to +125°C Derate Linearity at 12mW/°C to 200mW DEVICE DISSIPATION PER OUTPUT TRANSISTOR FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Types) 100mW OPERATING-TEMPERATURE RANGE (Tatg) STORAGE TEMPERATURE (Tatg) At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max +265°C

OPERATING CONDITIONS AT TA = 25°C Unless Otherwise Specified

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges

Characteristic	V _{DD}	Min.	Max.	Units V	
Supply Voltage Range (T _A): (Full Package Temperature Range)	-	3	18		
	5	150	-	ns	
Set-Up Time (ts)	10	70	_	ns	
	15	40		ns	
	5	0	_	ns	
Hold Time (tH)	10	0	_	ns	
	15	0	-	ns	
	5	400	_	ns	
Strobe Pulse Width (t _W)	10	160		ns	
· ·	15	100	_	ns	

CD4511B Types

STATIC ELECTRICAL CHARACTERISTICS

	TE	ST CON	DITIO	NS	LIMITS AT INDICATED TEMPERATURES (°C							
					LI	IMITS AT	T INDIÇA	ATED TE	EMPER#	TURES	(oc)	
CHARACTERISTIC	Іон	v _o	VIN	V _{DD}		ſ	Γ		Ι	+25	-	Units
	(mA)	(V)	(V)	(V)	-55	-40	+85	+125	Min.	Тур.	Max.	
Quiescent Device		_	_	5	5	5	150	150	_	0.04	5	
Current: IDD			_	10	10	10	300	300	_	0.04	10	μА
Max,			_	15	20	20	600	600		0.04	20	۳.
			_	20	100	100	3000	3000	-	0.08	100	
Output Voltage:				_	0.05							
Law Lavel Ma			0,5	5 10			0.05 0.05		· -	0	0.05	١,,
Low-Level VOL Max.		<u> </u>	0,10	15			0.05		-	0	0.05	: V
IVIGA.	<u> </u>	<u> </u>							<u> </u>		0.05	<u> </u>
11: 1 1 1 1	· ·	-	0,5	5	4	4	4.2	4.2	4.1	4.55		
High-Level VOH	_	_	0,10	10 15	9	9	9.2	9.2	9.1	9.55	-	٧
Min.			0.15	15	14	14	14.2.	14.2	14.1	14.55		
Input Low	_	0.5,3.8		5			1.5			_	1.5	
Voltage, VIL	_	1,8.8	-	10			3		-		3	v
Max.		1.5,13.8		15	4			-	_	4		
Input High	-	0.5,3.8		5			3.5		3.5	-	_	
Voltage, V _{IH}	_	1,8.8		10			7		7	_	_	V
		1.5,13.8		15			11		11		-	
	0			4	4.0	4.0	4.20	4.20	4.10	4.55		
	5	-						_		4.25		
	10			5	3.80	3.80	3.90	3.90	3.90	4.10	_	v
	15		-			-	3.50	3.50		3.95	_	
	20				3.55	3.55	3.30	_	3.40	3.75		
	25			•	3.40	3.40	-		3.10	3.55	~	
	0			•	9.0	9.0	9.20	9.20	9.10	9.55	-	
Output Drive	5					-				9.25	-	i
Voltage:	10	-	-	ΙΙ,	8.85	8.85	9.00	9.00	9.00	9.15	-	v
High Level VOH	15	-	-	10	_		-	- '	_	9.05		
Min.	20	_	-		8.70	8.70	8.40	8.40	8.60	8.90		
	25	-	_		8.60	8.60		_	8.30	8.75	. –	
	0			🛊	14.0	14.0	14.20	14.20	14.10	14.55	_	
	5							-		14.30		
	10			15	13.90	13.90	14.0	14.0	14.0	14.20		V
	15 20					- 12.75	1250	- 12.50		14.10		
	25				13.75 13.65	13.75 13.65	13.50	13.50	13.70	13.95		
	25		_		13.05	13.65			13.50	13.80		
Output Low												
(Sink) Current,	_	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	_	
l _{OL}		0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6		mA
Min.	-	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8		
Input Current, I _{IN} Max.	-	0,18	0,18	18	±0.1	±0.1	±1	±1	-	±10-5	±0.1	μΑ

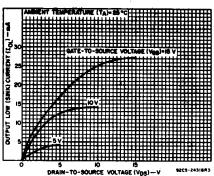


Fig. 1 — Typical output low (sink) current characteristics.

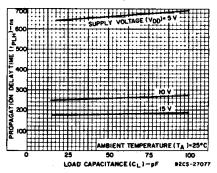


Fig. 2 — Typical data-to-output, low-to-high-level propagation dalay time as a function of load capacitance.

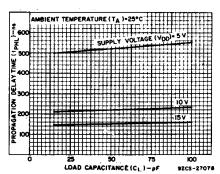


Fig. 3 — Typical data-to-output, high-to-low-level propagation delay time as a function of load capacitance.

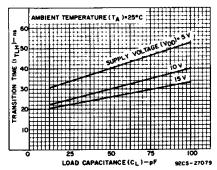


Fig. 4 — Typical low-to-high-level transition time as a function of load capacitance.

CD4511B Types

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A = 25^{\circ}C$, Input t_r , $t_f = 20$ ns, C_L = 50 pF, R_L = 200 k Ω

CHARACTERISTIC	Test Conditions	A	LIMITS All Package	UNITS	
X	Y _{DD} Volts	Min.	Тур.	Max.	
Propagation Delay Time:	5	_	520	1040	
(Data)	10	_	210	420	ns
High-to-Low Level, tpHL	15	-	150	300	
	5	_	660	1320	
Low-to-High Level, tPLH	10	l –	260	520	ns
	15	_	180	360	<u> </u>
Propagation Delay Time:	5	_	350	700	
(BL)	10	-	175	350	ns
High-to-Low Level, tpHL	15	_	125	250	
	5		400	800	
> Low-to-High Level, tpLH	10	_	175	350	ns
	15	- ,	150	300	
Propagation Delay Time:	5	-	250	500	
(LT)	10	-	125	250	ns
High-to-Low Level, tpHL	15		85	170	
	5	_	150	300	
Low-to-High Level, tPLH	10	_	75	150	ns
	15	_	50	100	
Transition Time:	. 5	_	40	80	
	10	-	30	60	пs
Low-to-High Level, tTLH	15		25	50	٠
	5	-	125	310	
	10	_	75	185	ns
High-to-Low Level, tTHL	15	_	65	160	
Minimum Co. Ha Ti	5	150	75	_	
Minimum Set-Up Time, tS	10	70	35	-	ns
	15	40	20	_	
	5	0	-75	_	
Minimum Hold Time, tH	10	0	-35	_	ns
	15	0	-20	_	
6. I B. W	5	400	200	_	
Strobe Pulse Width, t _W	10	160	80	. —	ns
	15	100	50		
Input Capacitance, CIN			5	7.5	pF

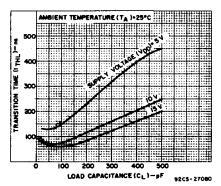


Fig. 5 - Typical high-to-low transition time as a function of load capacitance.

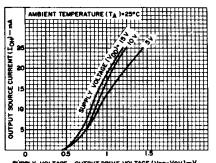


Fig. 6 - Typical voltage drop (V_{DD} to output) vs. output source current as a function of supply.

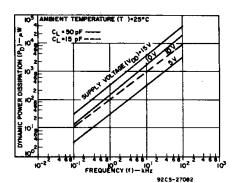
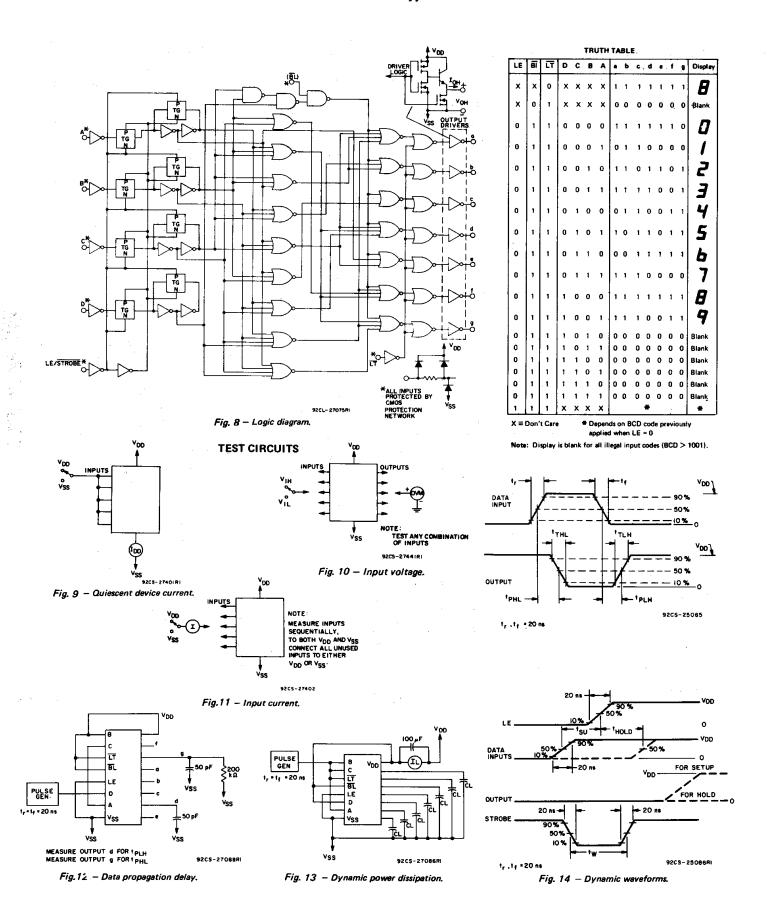
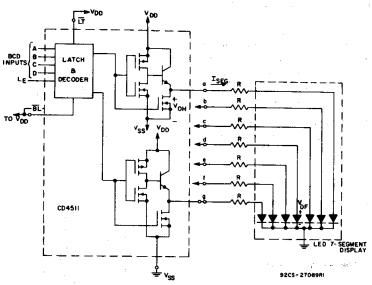


Fig. 7 - Typical dynamic power dissipation characteristics.

CD4511B Types



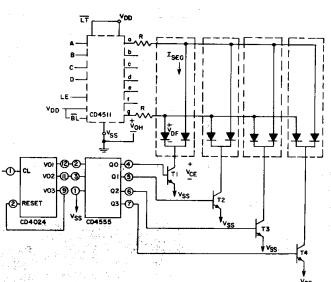
APPLICATIONS Interfacing with Various Displays



Duty Cycle = 100%

ISEG = IDIODEAVG. = 20 mA at Luminous Intensity/Segment = 250 microcandles

Fig. 15 - Driving common-cathode 7-segment LED displays (example Hewlet-Packard 5082-7740).



Multiplexing Scheme Showing 2 of 7 Segments Connected

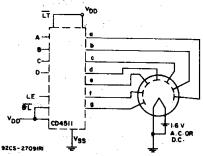
Transistors T₁-T₄ (RCA-2N3053 or 2N2102) have I_C Max.rating >7xI_{SEG}

Duty Cycle = 25% I SEG = $^{[I]}$ DIODE_{AVG} I × 4 $_{R}$ = $^{(V}$ OH - V DF - V CE I

ISEG

All unused inputs on CD4555 are connected to V_{DD} or V_{SS}

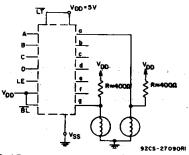
Fig. 18 — Multiplexing with common-cathode 7-segment LED displays (example Hewlet-Packard 5082-7404 4 character display or 4 discrete Monosanto Man 3 displays).



A medium-brightness intensity display can be obtained with low-voltage fluorescent displays such as the Tung-Sol Digivac S/G** Series.

**Trademark Tung-Sol Division Wagner Electric Co.

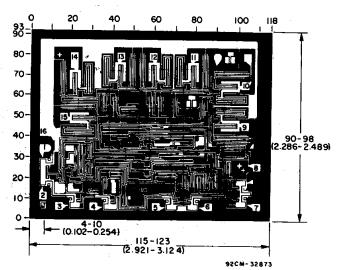
Fig. 16 — Driving low-voltage fluorescent displays.



2 of 7 Segments Shown Connected

Resistors R from V_{DD} to each 7-segment driver output are chosen to keep all Numitron segments slightly on and warm.

Fig. 17 — Driving incandescent displays (RCA Numitron DR2000 series displays).



Dimensions and pad layout for CD45118 chip.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3}) inch).

14 LEADS SHOWN



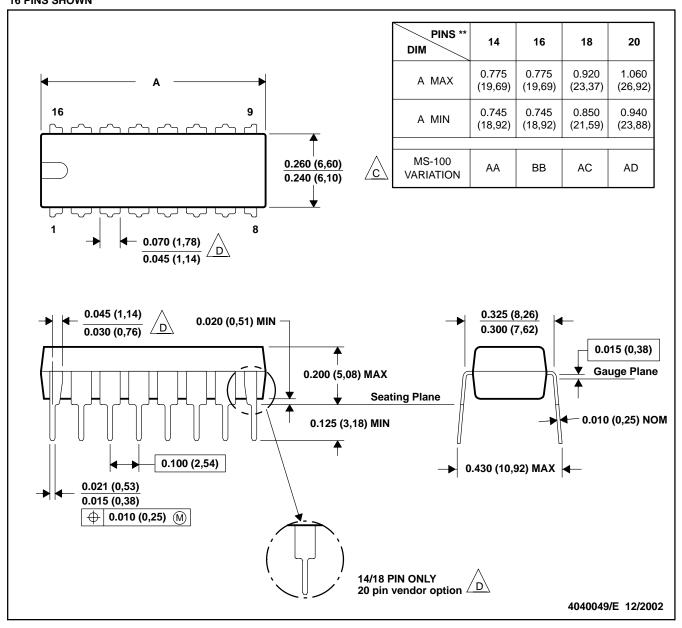
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

Falls within JEDEC MS-001, except 18 and 20 pin minimum body Irngth (Dim A).

The 20 pin end lead shoulder width is a vendor option, either half or full width.

1

MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

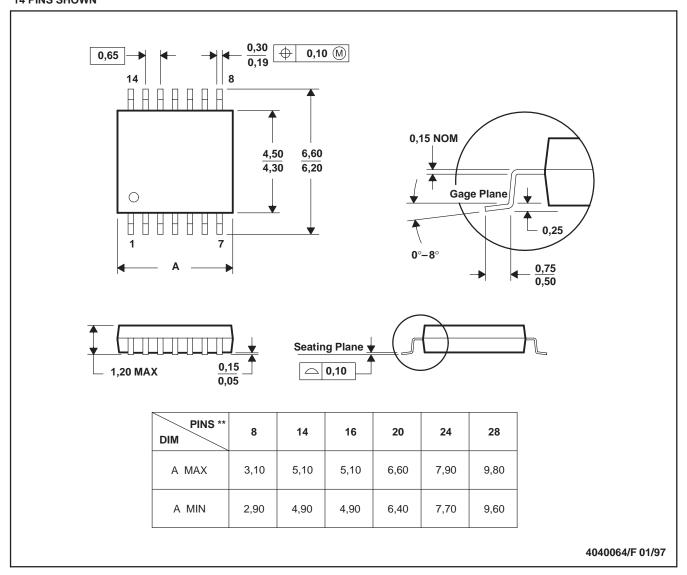
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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